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► **To cite this version:**

Benjamin Kiendl, Michael Drisch, Fabian Keppner, Ann-Christin Pöppler, Benedikt Knichelmann, et al.. Surface structure and spectroscopie properties of fluorinated diamond materials. SBDD XXIII - Hasselt Diamond Workshop 2018, Mar 2018, Hasselt, Belgium. pp.121. cea-04157398

HAL Id: cea-04157398

<https://cea.hal.science/cea-04157398>

Submitted on 10 Jul 2023

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Surface structure and spectroscopic properties of fluorinated diamond materials

Benjamin Kiendl,¹ Michael Drisch,² Fabian Keppner,² Ann-Christin-Pöppler,¹ Benedikt Knichelmann,¹ Amélie Venerosy,³ Hugues Girard,³ Jean-Charles Arnault,³ Maik Finze,² Sneha Choudhury,⁴ Tristan Petit,⁴ Anke Krueger¹

¹*Institute of Organic Chemistry, Julius-Maximilians-Universität Würzburg, Am Hubland, Würzburg, Germany*

²*Institute of Inorganic Chemistry, Julius-Maximilians-Universität Würzburg, Am Hubland, Würzburg, Germany*

³*CEA-LIST, Saclay, France*

⁴*Helmholtz-Zentrum für Neue Materialien und Energie GmbH Berlin, Germany*

anke.krueger@uni-wuerzburg.de

Depending on the surface termination the electronic properties of diamond materials can be varied over a wide range. Besides the usual hydrogenated and oxygenated diamond surface – typically achieved upon plasma treatment in a suitable gas atmosphere – the termination with fluorine is of special interest. It is well known that fluorination generates a highly hydrophobic and lubricating surface. Also the strong electron-withdrawing nature of fluorine bound to carbon atoms plays a role when considering the effect of surface fluorination of diamond as a means to tune its optical and electronic properties. Fluorination of bulk diamond has been achieved in the past using different plasma techniques e.g. with XeF₂ or CF₄ as the fluorine source, electrochemical fluorination or with thermal fluorination techniques.¹

For submicron diamond particles, several methods including the thermal gas phase fluorination,² the fluorination using XeF₂³ and the grafting of perfluorinated alkyl moieties⁴ have been reported. The resulting diamond materials have been characterized using infrared, Raman and XPS analysis to prove the efficient grafting of fluorine to the diamond surface and the modified materials properties.

Additionally, the fluorinated diamond was investigated using advanced solid-state NMR techniques enabling the structural characterization of the existing fluorinated surface structures. The results were supported by theoretical calculations.

Using the reported wet-chemical fluorination technique it is now possible to fluorinate all kinds of diamond materials in a mild and highly efficient way enabling the production of functional diamond materials for applications in catalysis, tribology or medicine.

This work has received funding from the European Union's Horizon 2020 Program under Grant Agreement n° 665085 (DIACAT).

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